

TC74ACT574P, TC74ACT574F, TC74ACT574FT

Octal D-Type Flip-Flop with 3-State Output

The TC74ACT574 is an advanced high speed CMOS OCTAL FLIP-FLOP fabricated with silicon gate and double-layer metal wiring C²MOS technology.

It achieves the high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation.

This devices may be used as a level converter for interfacing TTL or NMOS to High Speed CMOS. The inputs are compatible with TTL, NMOS and CMOS output voltage levels.

These 8-bit D-type flip-flops are controlled by a clock input (CK) and a output enable input (\overline{OE}).

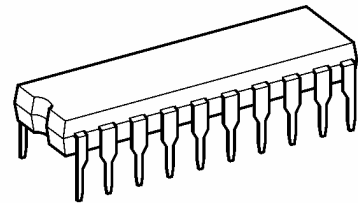
When the \overline{OE} input is high, the eight outputs are in a high impedance state.

All inputs are equipped with protection circuits against static discharge or transient excess voltage.

Features

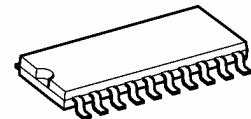
- High speed: $f_{\max} = 180 \text{ MHz}$ (typ.) at $V_{CC} = 5 \text{ V}$
- Low power dissipation: $I_{CC} = 8 \mu\text{A}$ (max) at $T_a = 25^\circ\text{C}$
- Compatible with TTL outputs:
 $V_{IL} = 0.8 \text{ V}$ (max), $V_{IH} = 2.0 \text{ V}$ (min)
- Symmetrical output impedance:
 $|I_{OH}| = I_{OL} = 24 \text{ mA}$ (min) Capability of driving 50Ω transmission lines.
- Balanced propagation delays: $t_{pLH} \approx t_{pHL}$
- Pin and function compatible with 74F574

TC74ACT574P



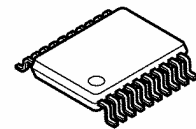
DIP20-P-300-2.54A

TC74ACT574F



SOP20-P-300-1.27A

TC74ACT574FT

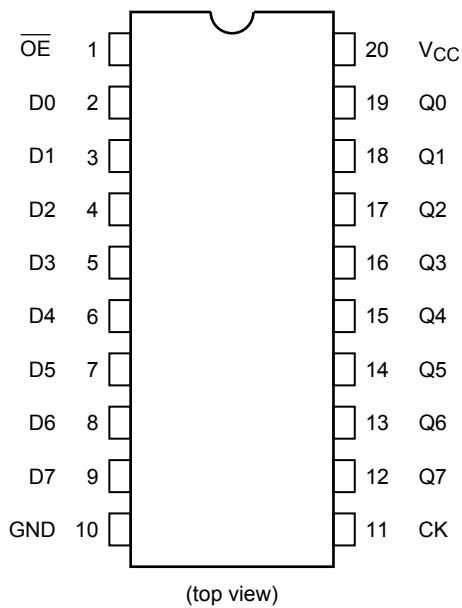


TSSOP20-P-0044-0.65A

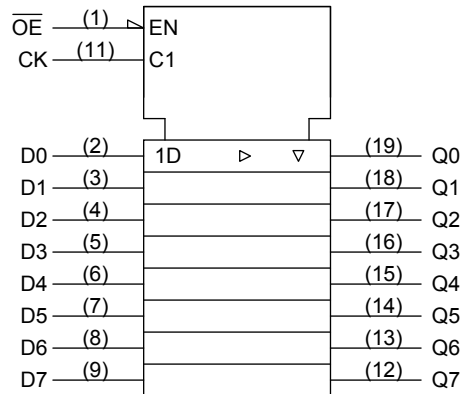
Weight

DIP20-P-300-2.54A	: 1.30 g (typ.)
SOP20-P-300-1.27A	: 0.22 g (typ.)
TSSOP20-P-0044-0.65A	: 0.08 g (typ.)

Pin Assignment



IEC Logic Symbol

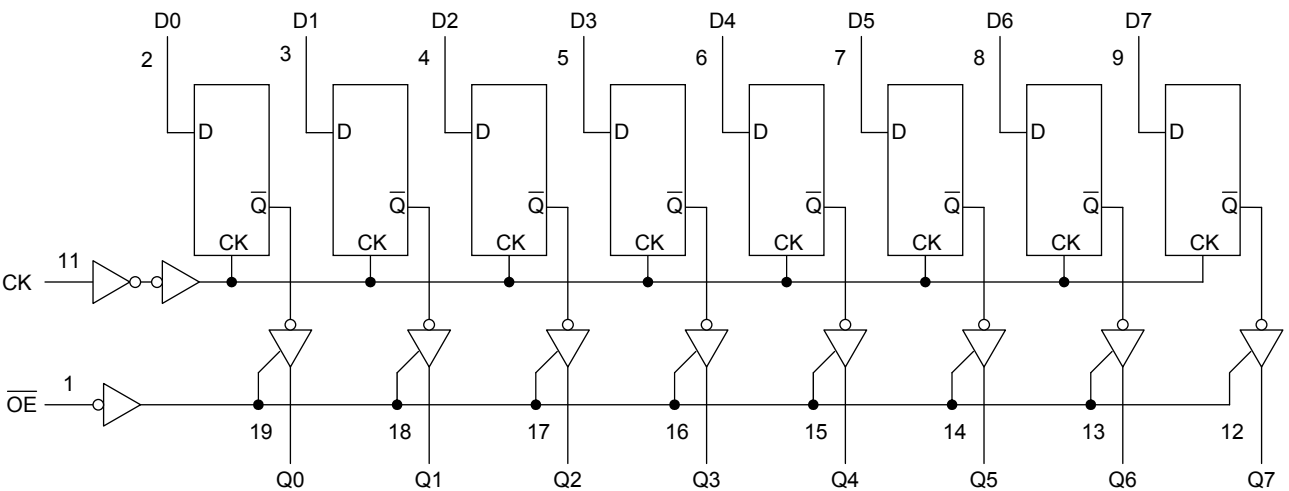


Truth Table

Inputs			Output
\overline{OE}	CK	D	Q
H	X	X	Z
L		X	Q_n
L		L	L
L		H	H

X: Don't care
Z: High impedance
 Q_n : No change

System Diagram



Absolute Maximum Ratings (Note 1)

Characteristics	Symbol	Rating	Unit
Supply voltage range	V_{CC}	-0.5 to 7.0	V
DC input voltage	V_{IN}	-0.5 to $V_{CC} + 0.5$	V
DC output voltage	V_{OUT}	-0.5 to $V_{CC} + 0.5$	V
Input diode current	I_{IK}	± 20	mA
Output diode current	I_{OK}	± 50	mA
DC output current	I_{OUT}	± 50	mA
DC V_{CC} /ground current	I_{CC}	± 200	mA
Power dissipation	P_D	500 (DIP) (Note 2)/180 (SOP/TSSOP)	mW
Storage temperature	T_{stg}	-65 to 150	°C

Note 1: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc.).

Note 2: 500 mW in the range of $T_a = -40$ to 65°C . From $T_a = 65$ to 85°C a derating factor of -10 mW/°C should be applied up to 300 mW.

Operating Ranges (Note)

Characteristics	Symbol	Rating	Unit
Supply voltage	V_{CC}	4.5 to 5.5	V
Input voltage	V_{IN}	0 to V_{CC}	V
Output voltage	V_{OUT}	0 to V_{CC}	V
Operating temperature	T_{opr}	-40 to 85	°C
Input rise and fall time	dt/dV	0 to 10	ns/V

Note: The operating ranges must be maintained to ensure the normal operation of the device. Unused inputs must be tied to either VCC or GND.

Electrical Characteristics

DC Characteristics

Characteristics	Symbol	Test Condition		V _{CC} (V)	Ta = 25°C			Ta = -40 to 85°C		Unit
					Min	Typ.	Max	Min	Max	
High-level input voltage	V _{IH}	—		4.5 to 5.5	2.0	—	—	2.0	—	V
Low-level input voltage	V _{IL}	—		4.5 to 5.5	—	—	0.8	—	0.8	V
High-level output voltage	V _{OH}	V _{IN} = V _{IH} or V _{IL}	I _{OH} = -50 µA	4.5	4.4	4.5	—	4.4	—	V
			I _{OH} = -24 mA	4.5	3.94	—	—	3.80	—	
			I _{OH} = -75 mA (Note)	5.5	—	—	—	3.85	—	
Low-level output voltage	V _{OL}	V _{IN} = V _{IH} or V _{IL}	I _{OL} = 50 µA	4.5	—	0.0	0.1	—	0.1	V
			I _{OL} = 24 mA	4.5	—	—	0.36	—	0.44	
			I _{OL} = 75 mA (Note)	5.5	—	—	—	—	1.65	
3-state output off-state current	I _{OZ}	V _{IN} = V _{IH} or V _{IL} V _{OUT} = V _{CC} or GND		5.5	—	—	±0.5	—	±5.0	µA
Input leakage current	I _{IN}	V _{IN} = V _{CC} or GND		5.5	—	—	±0.1	—	±1.0	µA
Quiescent supply current	I _{CC}	V _{IN} = V _{CC} or GND		5.5	—	—	8.0	—	80.0	µA
	I _C	Per input: V _{IN} = 3.4 V Other input: V _{CC} or GND		5.5	—	—	1.35	—	1.5	mA

Note: This spec indicates the capability of driving 50 Ω transmission lines.

One output should be tested at a time for a 10 ms maximum duration.

Timing Requirements (input: t_r = t_f = 3 ns)

Characteristics	Symbol	Test Condition	Ta = 25°C	Ta = -40 to 85°C	Unit	
			VCC (V)	Limit		Limit
Minimum pulse width (CK)	t _w (H) t _w (L)	—	5.0 ± 0.5	5.0	5.0	ns
Minimum set-up time	t _s	—	5.0 ± 0.5	3.0	3.0	ns
Minimum hold time	t _h	—	5.0 ± 0.5	2.0	2.0	ns

AC Characteristics ($C_L = 50 \text{ pF}$, $R_L = 500 \Omega$, input: $t_r = t_f = 3 \text{ ns}$)

Characteristics	Symbol	Test Condition		Ta = 25°C			Ta = -40 to 85°C		Unit
			V _{CC} (V)	Min	Typ.	Max	Min	Max	
Propagation delay time (CK-Q)	t _{pLH} t _{pHL}	—	5.0 ± 0.5	—	6.2	10.1	1.0	11.5	ns
Output enable time	t _{pZL} t _{pZH}	—	5.0 ± 0.5	—	6.3	10.5	1.0	12.0	ns
Output disable time	t _{pLZ} t _{pHZ}	—	5.0 ± 0.5	—	6.6	9.6	1.0	11.0	ns
Maximum clock frequency	f _{max}	—	5.0 ± 0.5	85	160	—	85	—	MHz
Input capacitance	C _{IN}	—		—	5	10	—	10	pF
Output capacitance	C _{OUT}	—		—	10	—	—	—	pF
Power dissipation capacitance	C _{PD}	(Note)		—	33	—	—	—	pF

Note: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:

$$I_{CC}(\text{opr}) = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/8 \text{ (per F/F)}$$

And the total C_{PD} when n pcs. of F/F operate can be gained by the following equation:

$$C_{PD}(\text{total}) = 21 + 12 \cdot n$$

Package Dimensions

DIP20-P-300-2.54A

Unit : mm

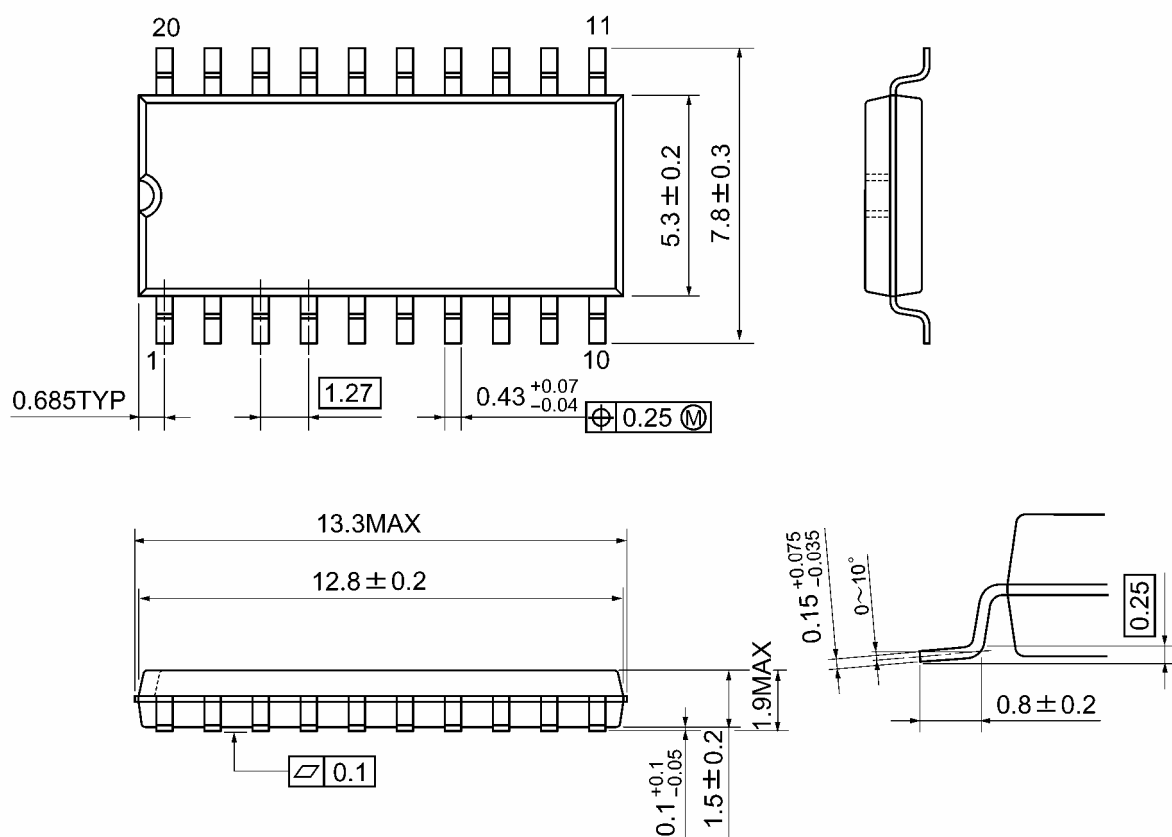


Weight: 1.30 g (typ.)

Package Dimensions

SOP20-P-300-1.27A

Unit: mm

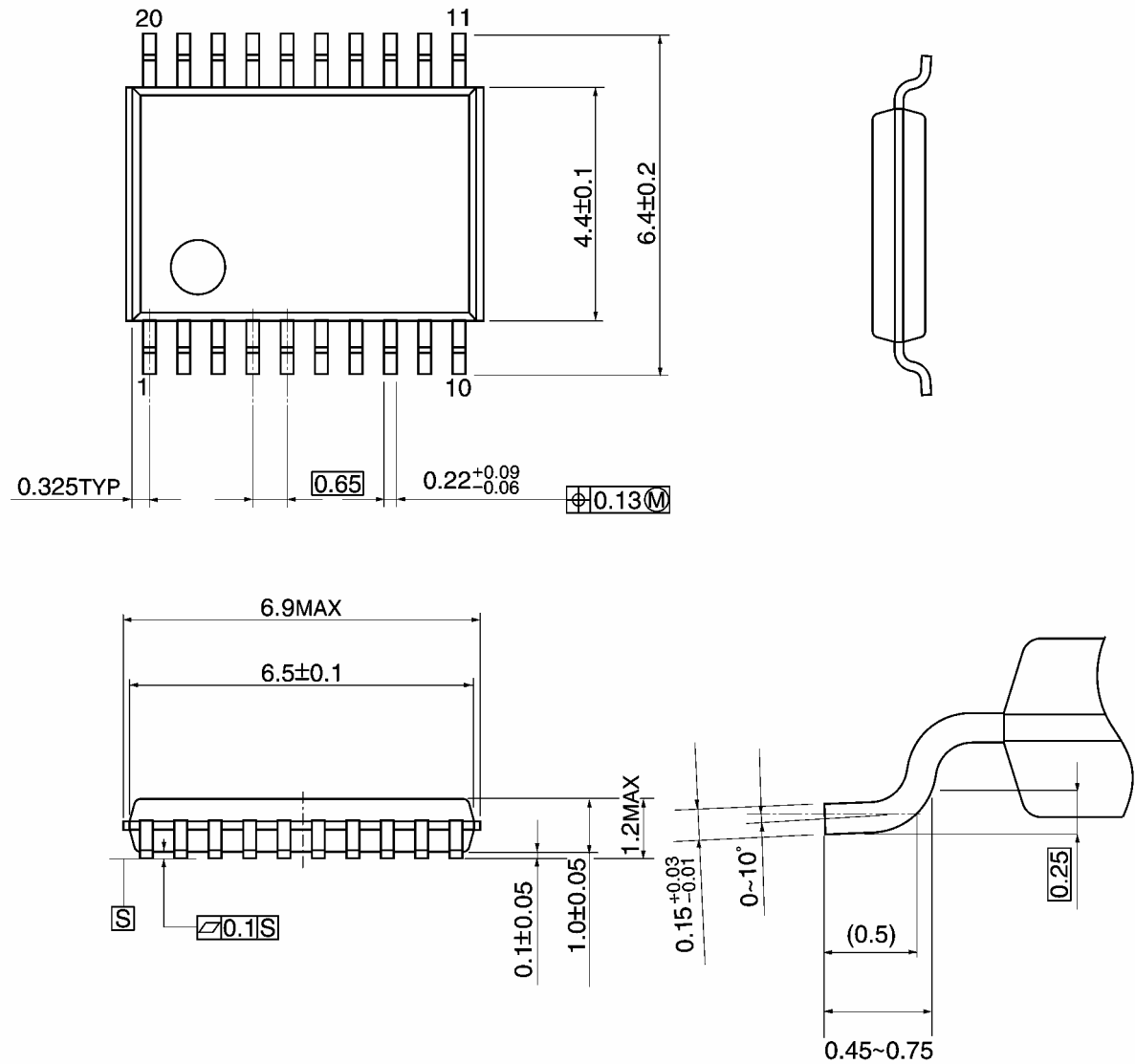


Weight: 0.22 g (typ.)

Package Dimensions

TSSOP20-P-0044-0.65A

Unit: mm



Weight: 0.08 g (typ.)

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20070701-EN GENERAL

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